

KPT081M31

Product code: KPT081M31

Manufacturer: Kyosemi Corporation

Features:

- NPN photransistor
- Transparent epoxy mold
- Low leak current

Applications:

- Optical switches
- Optical encoders
- Photo-isolator
- Cameras stroboscopes
- Infrared sensors
- Automatic control apparatus

Half Angle (deg)	60
Package	φ3 plastic mold
Peak sens. wavelenght (nm)	800
Photo Current Vce = 5 V	7 (mA) 1000 (Ix)
Sensitive Area (mm)	0.64 x 0.64
Typology	Silicon Phototransistors